

Low Drop Voltage Regulator

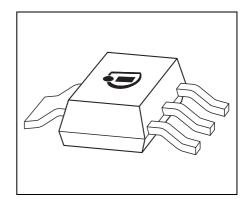
TLE 4266-2





Features

- Fixed output voltage 5.0 V or 3.3 V
- Output voltage tolerance ≤ ±2%, ±3%
- 150 mA current capability
- Very low current consumption
- Low-drop voltage
- Overtemperature protection
- Reverse polarity proof
- Wide temperature range
- Suitable for use in automotive electronics
- Inhibit
- Green Product (RoHS compliant)
- AEC Qualified



Functional Description

The TLE 4266-2 is a monolithic integrated low-drop fixed voltage regulator which can supply loads up to 150 mA. It can be switched on and off by the $\overline{\text{INH}}$ pin. It is functional compatible to the TLE 4266, but with a reduced quiescent current of << 1 μ A in OFF mode and 40 μ A in ON mode. The TLE 4266-2 is especially designed for all applications that require very low quiescent current in ON and OFF mode. The device is available in the small surface mounted PG-SOT223-4 package. It is pin compatible to the TLE 4266 G. It is designed to supply microprocessor systems under the severe condition of automotive applications and therefore it is equipped with additional protection against over load, short circuit and overtemperature. Of course the TLE 4266-2 can be used in other applications, where a stabilized voltage and the inhibit feature is required.

And input voltage $V_{\rm I}$ up to 45 V is regulated to $V_{\rm Q}$ = 5 V (TLE 4266-2 G) or $V_{\rm Q}$ = 3.3 V (TLE 4266-2 GSV33) with an accuracy of ±3%. For the 5 V device an accuracy of ±2% is kept for a load current range up to 50 mA.

The device operates in the temperature range of $T_{\rm j}$ = -40 to 150 °C. A High level at the $\overline{\rm INH}$ pin switches the regulator on.

Туре	Package
TLE 4266-2 G	PG-SOT223-4
TLE 4266-2 GSV33	PG-SOT223-4

Data Sheet 1 Rev. 1.4, 2008-03-10



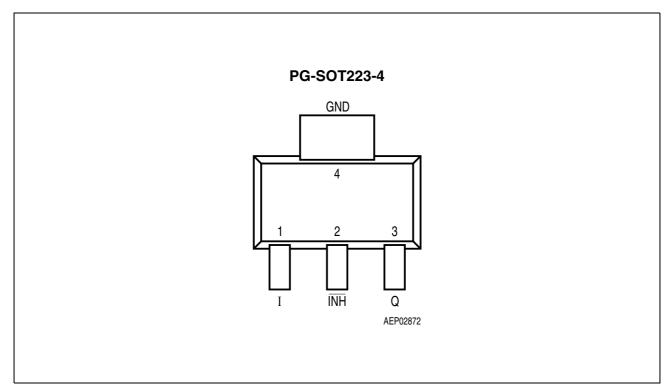


Figure 1 Pin Configuration (top view)

Table 1 Pin Definitions and Functions TLE 4266-2 G, TLE 4266-2 GSV33

Pin	Symbol	Function
1	I	Input voltage ; block to ground directly at the IC with a ceramic capacitor.
2	ĪNH	Inhibit input; high level turns IC on, integrated pull-down resistor.
3	Q	Output voltage; block to ground with a capacitor $C_{\rm Q} \ge$ 10 $\mu{\rm F}$, ESR \le 4 Ω
4	GND	Ground

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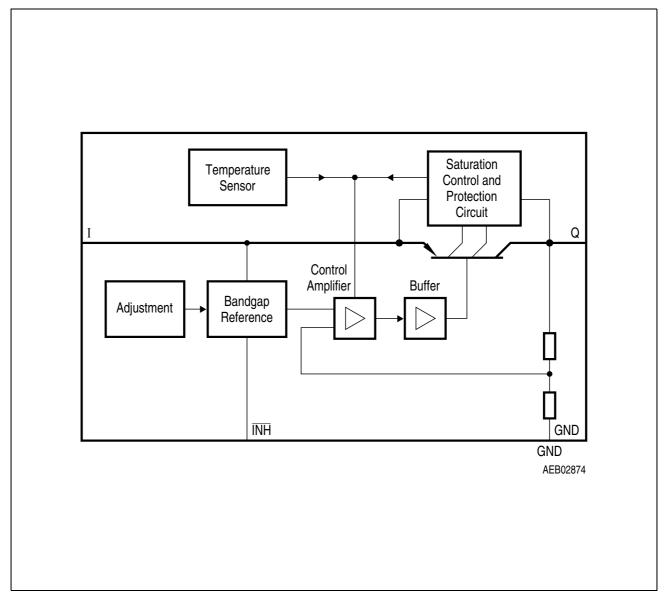


Figure 2 Block Diagram

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Table 2 Absolute Maximum Ratings

 $T_{\rm i}$ = -40 to 150 °C

Parameter	Symbol	Limit Values		Unit	Notes	
		Min. Max.				
Input I	•	•	•	•		
Voltage	V_{I}	-42	45	V	_	
Current	I_{l}	_	_	_	internally limited	
Inhibit INH			•			
Voltage	$V_{\overline{INH}}$	-42	45	V	_	
Output Q	<u> </u>		<u> </u>			
Voltage	V_{Q}	-0.3	32	V	_	
Current	I_{Q}	_	_	_	internally limited	
GND	<u> </u>		<u> </u>			
Current	I_{GND}	50	_	mA	_	
Temperature			•			
Junction temperature	T_{j}	_	150	°C	_	
Storage temperature	T_{S}	-50	150	°C	_	
Thermal Resistance	<u> </u>		<u> </u>			
Junction ambient	$R_{\text{thj-a}}$	_	81	K/W	PG-SOT223-4 ¹⁾	
Junction case	$R_{ m thj-pin4}$	_	18	K/W	PG-SOT223-4	
Operating Range		•	•	•		
Input voltage	V_{l}	5.5	45	V	TLE 4266-2 G	
		4.4	45	V	TLE 4266-2 GSV33	
Junction temperature	$T_{\rm j}$	-40	150	°C	_	

¹⁾ Worst case, regarding peak temperature; zero airflow; mounted an a PCB 80 × 80 × 1.5 mm³, heat sink area 300 mm².

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Table 3 Characteristics

 $V_{\rm I}$ = 13.5 V; $V_{\overline{\rm INH}}$ = 5 V; -40 °C ≤ $T_{\rm j}$ ≤ 125 °C unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition	
		Min.	Тур.	Max.	=		
Output voltage	V_{Q}	4.85	5.0	5.15	V	TLE 4266-2 G; $5 \text{ mA} \le I_{\text{Q}} \le 100 \text{ mA};$ $6 \text{ V} \le V_{\text{I}} \le 21 \text{ V}$	
		4.9	5.0	5.1	V	TLE 4266-2 G; 5 mA $\leq I_{\rm Q} \leq$ 50 mA; 9 V $\leq V_{\rm I} \leq$ 16 V	
Output voltage	V_{Q}	3.20	3.30	3,40	V	TLE 4266-2 GSV33; 5 mA \leq $I_{\rm Q} \leq$ 100 mA; 6 V \leq $V_{\rm I} \leq$ 21 V	
Output-current limitation	I_{Q}	150	200	500	mA	_	
Current consumption $I_q = I_l - I_Q$	I_{q}	_	0	1	μΑ	$V_{\overline{\text{INH}}} = 0 \text{ V}; T_{\text{j}} \leq 100 \text{ °C}$	
Current consumption $I_q = I_l - I_Q$	I_{q}	_	40	60	μΑ	$I_{\rm Q}$ = 100 μ A; $T_{\rm j} \le$ 85 °C	
		_	40	70	μΑ	$I_{\rm Q}$ = 100 μ A	
Current consumption $I_q = I_l - I_Q$	I_{q}	_	1.7	4	mA	$I_{\rm Q}$ = 50 mA	
Drop voltage	V_{Dr}	_	0.25	0.5	V	TLE 4266-2 G; $I_Q = 100 \text{ mA}^{1)}$	
Drop voltage	V_{Dr}	_	1.00	1.10	V	TLE 4266-2 GSV33; $I_{\rm Q}$ = 100 mA ²⁾	
Load regulation	ΔV_{Q}	_	50	90	mV	TLE 4266-2 G; I_Q = 1 to 100 mA; V_I = 6 V	
Load regulation	ΔV_{Q}	_	35	60	mV	TLE 4266-2 GSV33; $I_{\rm Q}$ = 1 to 100 mA; $V_{\rm I}$ = 6 V	
Line regulation	ΔV_{Q}	_	5	30	mV	TLE 4266-2 G; $V_{\rm I}$ = 6 V to 28 V; $I_{\rm Q}$ = 1 mA	
Line regulation	ΔV_{Q}	_	4	20	mV	TLE 4266-2 GSV33; $V_{\rm I}$ = 6 V to 28 V; $I_{\rm Q}$ = 1 mA	



Table 3 Characteristics (cont'd)

 $V_{\rm I}$ = 13.5 V; $V_{\overline{\rm INH}}$ = 5 V; -40 °C ≤ $T_{\rm j}$ ≤ 125 °C unless otherwise specified

1 ' 11411 '	J				•	
Parameter	Symbol	Limit Values		Unit	Test Condition	
		Min.	Тур.	Max.		
Power Supply Ripple Rejection	PSRR	_	68	_	dB	$f_{\rm r}$ = 100 Hz; $V_{\rm r}$ = 0.5 Vpp
Output Capacitor	C_{Q}	10	_	_	μF	ESR \leq 4 Ω at 10 kHz
Inhibit						
Inhibit on voltage	$V_{\overline{INH}, on}$	3.5	_	_	V	_
Inhibit off voltage	$V_{\overline{INH},\;off}$	_	_	0.8	V	_
Inhibit current	$I_{\overline{INH}}$	_	4	8	μΑ	$V_{\overline{\text{INH}}} = 5 \text{ V}$
Pull-down resistor	R _{INH}	_	1.0	_	МΩ	see I _{INH}

¹⁾ Drop voltage = $V_{\rm l}$ - $V_{\rm Q}$ (measured when the output voltage $V_{\rm Q}$ has dropped 100 mV from the nominal value obtained at $V_{\rm l}$ = 13.5 V).

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²⁾ Drop voltage = $V_{\rm l}$ - $V_{\rm Q}$ (measured when the output voltage $V_{\rm Q}$ has dropped 100 mV from the nominal value obtained at $V_{\rm l}$ = 13.5 V).



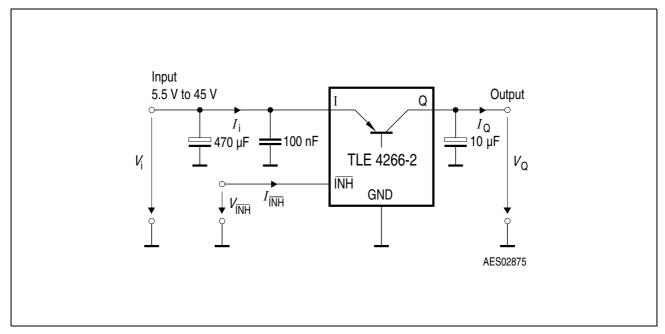


Figure 3 Measuring Circuit

Circuit Description and Application Information

In the TLE 4266-2 the output voltage is divided and compared to an internal reference of 2.5 V typical. The regulation loop controls the output to achieve an output voltage of 5 V with an accuracy of $\pm 2\%$ at an input voltage up to 45 V. The minimum required input voltage is $V_{\rm Q} + V_{\rm dr}$ with a drop voltage $V_{\rm dr}$ of max. 0.5 V (see "Typical Performance Characteristics" on Page 8) in case of the TLE 4266-2 G. The TLE 4266-2 GSV33 requires a minimum input voltage of 4.4 V.

The TLE 4266-2 can supply up to 150 mA. However for protection reasons at high input voltage above 25 V, the maximum output current is reduced (SOA protection).

Figure 3 shows a typical measuring circuit. For stability of the control loop the TLE 4266-2 output requires an output capacitor $C_{\rm Q}$ of at least 10 $\mu \rm F$ with a maximum permissible ESR of 4 Ω . Tantalum as well as multi layer ceramic capacitors are suitable.

At the input of the regulator an input capacitor is necessary for compensating line influences (100 nF ceramic capacitor recommended). A resistor of approx. 1 Ω in series with $C_{\rm I}$, can damp any oscillation occurring due the input inductivity and the input capacitor. In the measuring circuit shown in **Figure 3** an additional electrolytic input capacitor of 470 μ F is added in order to buffer supply line influences. This capacitor is recommended, if the device is sourced via long supply lines of several meters.

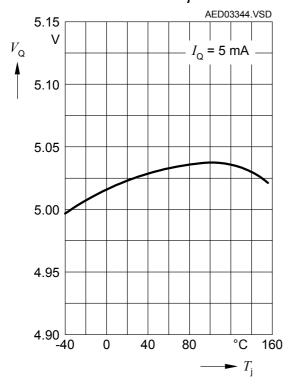
The TLE 4266-2 includes the Inhibit function. For a voltage above 3.5 V at the INH pin the regulator is switched on.

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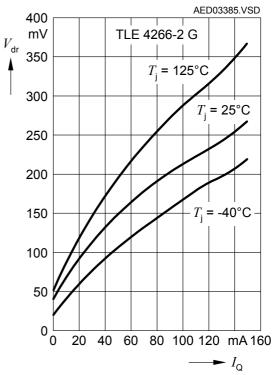


Typical Performance Characteristics

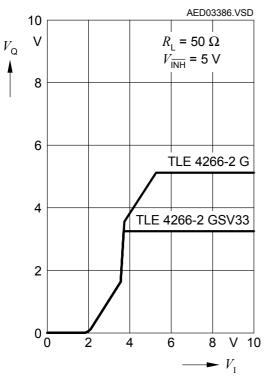
Output Voltage V_{Q} versus Junction Temperature T_{i}



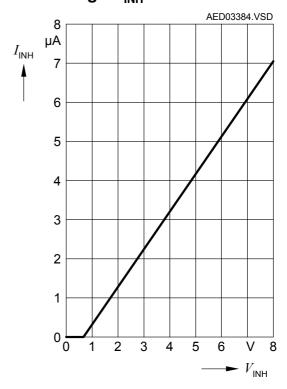
Drop Voltage $V_{ m dr}$ versus Output Current $I_{ m Q}$ (TLE 4266-2 G)



Output Voltage $V_{\rm Q}$ versus Input Voltage $V_{\rm I}$

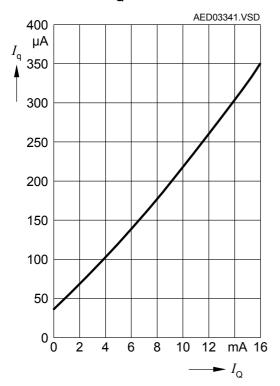


Inhibit Current $I_{\overline{\text{INH}}}$ versus Inhibit Voltage $V_{\overline{\text{INH}}}$

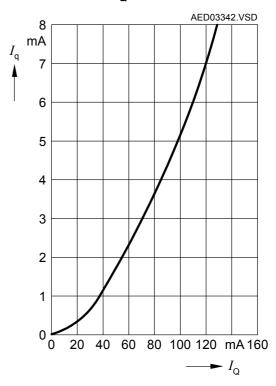




Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$



Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$



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Package Outlines

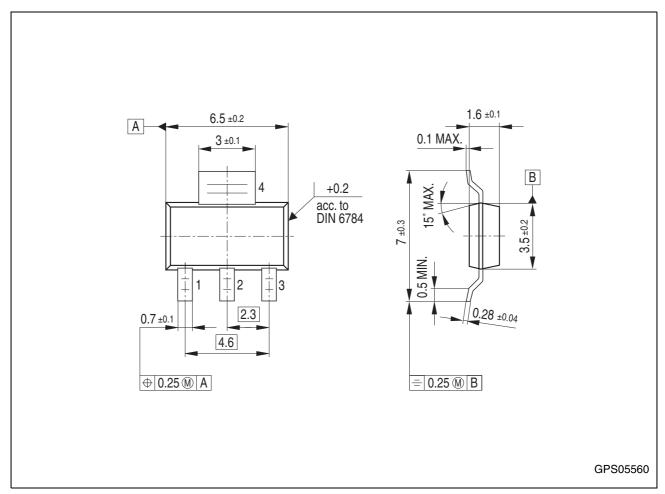


Figure 4 PG-SOT223-4 (Plastic Small Outline Transistor)

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": http://www.infineon.com/products.

SMD = Surface Mounted Device

Dimensions in mm



Revision History

Version	Date	Changes
Rev. 1.4	2008-03-10	Simplified package name to PG-SOT223-4. No modification of released product.
Rev. 1.3	2007-03-20	Initial version of RoHS-compliant derivate of TLE 4266-2 Page 1: AEC certified statement added Page 1 and Page 10: RoHS compliance statement and Green product feature added Page 1 and Page 10: Package changed to RoHS compliant version Legal Disclaimer updated

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